

2W005G THRU 2W10G

SILICON GLASS PASSIVATED BRIDGE RECTIFIERS

Reverse Voltage – 50 to 1000 V
Forward Current – 2 A

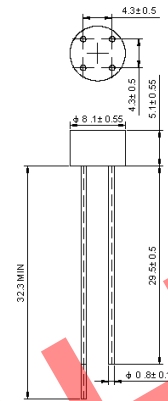
Features

- Rating to 1000 V PRV
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Glass passivated chip junction

Mechanical Data

- **Case:** WOM, Molded plastic
- **Polarity:** As marked on Body

WOM

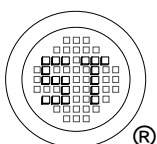


Dimensions in millimeters

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	2W005G	2W01G	2W02G	2W04G	2W06G	2W08G	2W10G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Output Current at $T_A = 55\text{ }^\circ\text{C}$	$I_{F(AV)}$	2							A
Peak Forward Surge Current, 8.3 ms Single Half-Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	50							A
Maximum Instantaneous Forward Voltage at 1 A	V_F	1							V
Maximum Reverse Current $T_A = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_A = 100\text{ }^\circ\text{C}$	I_R	10 1							μA mA
Operating and Storage Temperature Range	T_J, T_{Stg}	- 55 to + 150							$^\circ\text{C}$



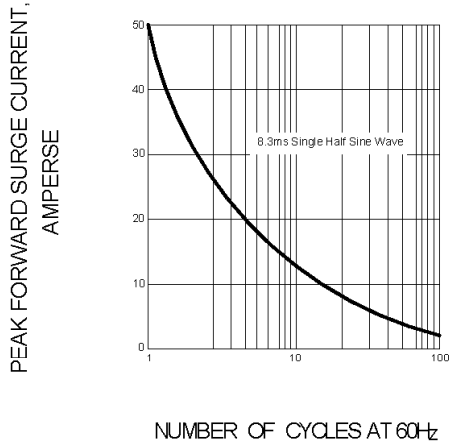
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Dated : 29/08/2008 B

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FIG.1 – PEAK FORWARD SURGE CURRENT



**FIG.2 – FORWARD DERATING CURVE
OUTPUT RECTIFIED CURRENT**

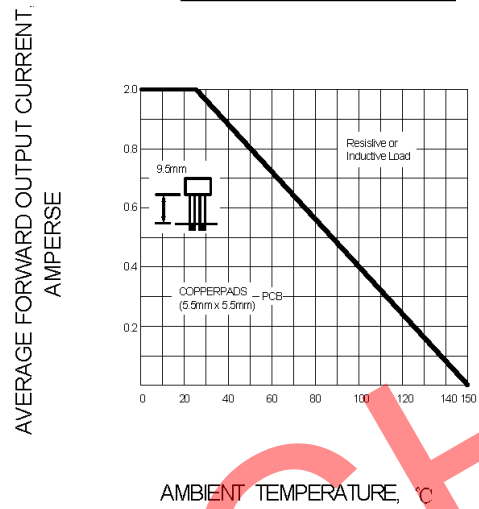


FIG.3 – TYPICAL FORWARD CHARACTERISTIC

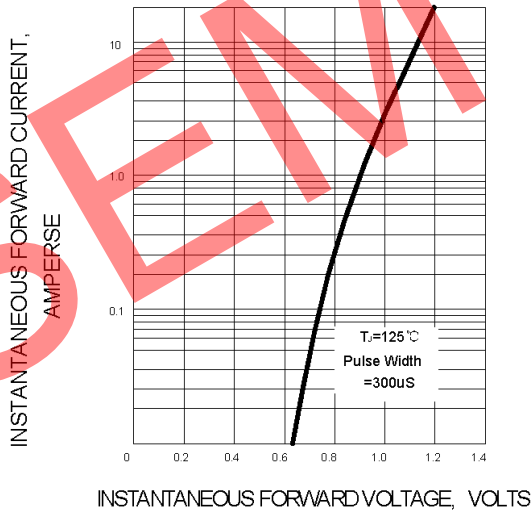
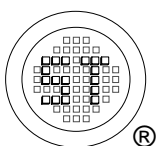
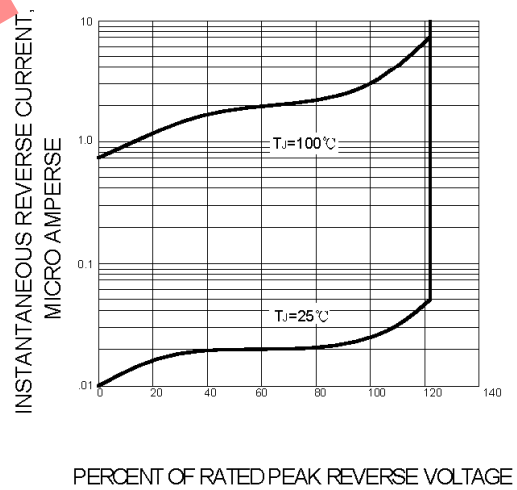


FIG.4 – TYPICAL REVERSE CHARACTERISTIC



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